NSN 5961-01-317-9374

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-9374 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.145 inches and 0.165 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.068 inches and 0.075 inches **Function For Which Designed:** Microwave **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc outside diameter **Capacitance Rating In Picofarads:** 0.36 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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